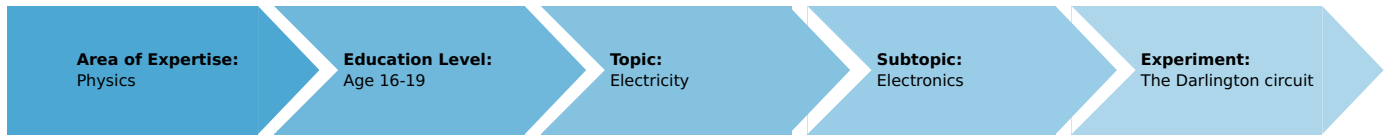


# The Darlington circuit (Item No.: P1402000)

## Curricular Relevance



### Difficulty



Difficult

### Preparation Time



10 Minutes

### Execution Time



10 Minutes

### Recommended Group Size



2 Students

### Additional Requirements:

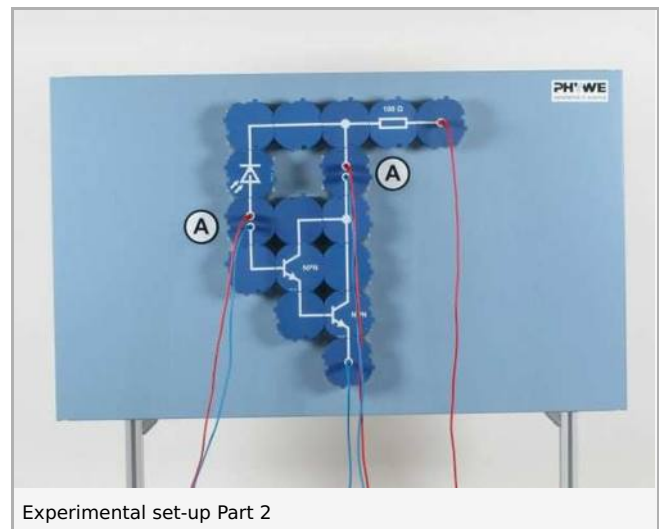
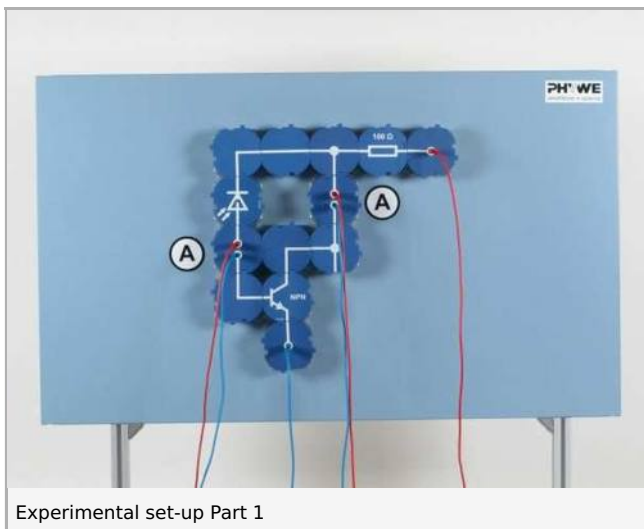
### Experiment Variations:

### Keywords:

## Principle and equipment

### Principle

It is to be shown that current amplification can be substantially increased by the combination of two transistors in a Darlington circuit.



## Equipment

Position No.	Material	Order No.	Quantity
1	Multimeter ADM2, demo., analogue	13820-01	2
2	PHYWE power supply, universal DC: 0...18 V, 0...5 A / AC: 2/4/6/8/10/12/15 V, 5 A	13500-93	1
3	Demo Physics board with stand	02150-00	1
4	Transistor BC337,module DB	09456-00	2
5	Clamp on holder	02164-00	1
6	Connector interrupted, module DB	09401-04	2
7	Junction, module DB	09401-10	2
8	Resistor 100 Ohm,module DB	09413-10	1
9	Photodiode,module DB	09453-00	1
10	Connector, straight, module DB	09401-01	2
11	Connector, angled, module DB	09401-02	4
12	Connector, T-shaped, module DB	09401-03	2
13	Boss head	02043-00	1
14	Universal clamp	37715-00	1
15	Support rod, stainless steel, 500 mm	02032-00	1
16	Flashlight, w/o battery,medium	08164-00	1
17	Connecting cord, 32 A, 1000 mm, red	07363-01	3
18	Connecting cord, 32 A, 1000 mm, blue	07363-04	3
19	Battery cell, 1.5 V, baby size, type C	07922-01	2

## Set-up and procedure

### 1st. Experiment

- Label the transistors as  $T_1$  and  $T_2$
- Set up the experiment as shown in Fig. 1 with transistor  $T_1$ ; select the 10 IJA measurement range for the measuring instrument in the base circuit
- Select the 3 mA measurement range for the measuring instrument in the collector circuit
- Set the power supply to a voltage of 6 V-
- Fix the torch to the edge of the board with the holding material and use it to so light the photodiode, that the photocurrent does not exceed the value of  $I_B = 5\mu A$
- Note the values measured for the base current and the collector current of the transistor
- Repeat this procedure using transistor  $T_2$

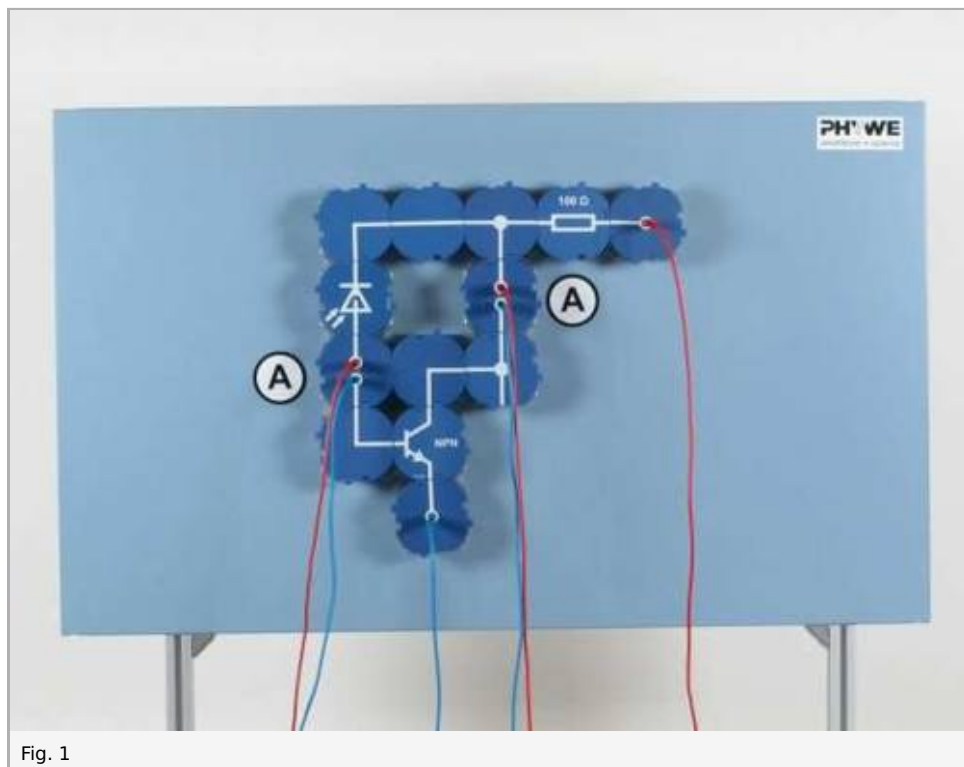


Fig. 1

### 2nd. Experiment

- **Extend the experimental set-up as shown in Fig. 2 and switch over to the 100 mA measurement range for the collector current  $I_{CD}$**
- **Note the value measured for the collector current  $I_{CD}$  of the Darlington circuit**
- **Illuminate the photodiode as in the 1st. experiment; note the value measured for the base current  $I_{BD}$  of the Darlington circuit**

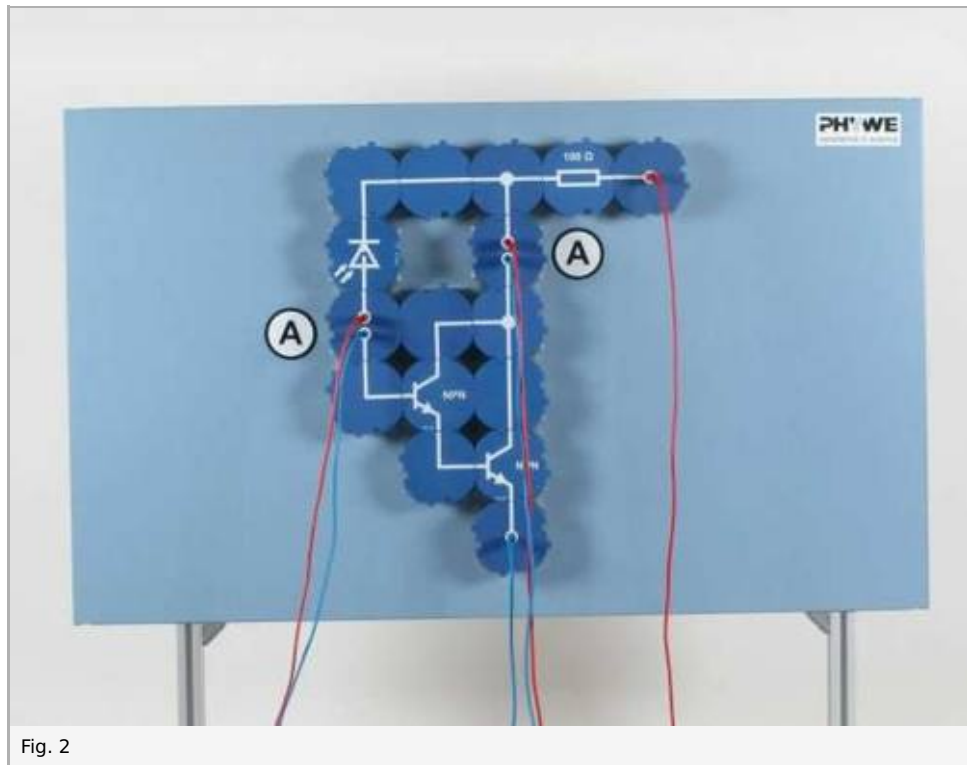


Fig. 2

## Observation and evaluation

### Observation

$$I_{CD} = 51 \text{ mA}$$

$$I_{BD} = 0.4 \text{ }\mu\text{A}$$

Table 1

Transistor	Base current	Collector current
T <sub>1</sub>	$I_{B1} = 3 \text{ }\mu\text{A}$	$I_{C1} = 1.25 \text{ mA}$
T <sub>2</sub>	$I_{B2} = 3 \text{ }\mu\text{A}$	$I_{C2} = 0.85 \text{ mA}$

### Evaluation

The photocurrent of the photodiode is amplified by transistor T<sub>1</sub> from  $I_{B1} = 3 \text{ }\mu\text{A}$  auf  $I_{C1} = 1,25 \text{ mA}$ . When the circuit is expanded to a Darlington circuit by a second transistor, then the current is amplified further from  $I_{C1} = 1,25 \text{ mA}$  to  $I_{CD} = 51 \text{ mA}$ . The current has so been increased by a factor of approx. 17,000.

In a Darlington circuit, the emitter current that is amplified by the first transistor is used as base current for the second transistor, where further amplification occurs. The total current amplification of a Darlington circuit is approximately equal to the product of the current amplifications of the individual transistors:

$$B_{ges} \approx B_1 \cdot B_2$$

Table 2

Transistor	Amplification
T <sub>1</sub>	$B_1 = \frac{I_{C1}}{I_{B1}} = 417$
T <sub>2</sub>	$B_2 = \frac{I_{C2}}{I_{B2}} = 283$
Darlington circuit	$B_{tot} = \frac{I_{CD}}{I_{BD}} = 127500$
	$B_1 \cdot B_2 = 118000$

### Remarks

The amplification values of the transistors used can differ greatly from each other. For this reason, the measured values determined may differ greatly from those given here. The 100 Ω resistor serves to limit the collector current and so to hinder thermal destruction of the transistors.